Low-ohmic single-pole double-throw analog switch

Rev. 1 — 23 May 2013

Product data sheet

1. General description

The NX3L1G3157-Q100 is a low-ohmic single-pole double-throw analog switch suitable for use as an analog or digital 2:1 multiplexer/demultiplexer. It has a digital select input (S), two independent inputs/outputs (Y0 and Y1) and a common input/output (Z). Schmitt trigger action at the digital input makes the circuit tolerant to slower input rise and fall times.

The NX3L1G3157-Q100 allows signals with amplitude up to V_{CC} to be transmitted from Z to Y0 or Y1; or from Y0 or Y1 to Z. Its low ON resistance (0.5 Ω) and flatness (0.13 Ω) ensures minimal attenuation and distortion of transmitted signals.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
 Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance:
 - 1.6 Ω (typical) at V_{CC} = 1.4 V
 - 1.0 Ω (typical) at V_{CC} = 1.65 V
 - 0.55 Ω (typical) at V_{CC} = 2.3 V
 - 0.50 Ω (typical) at V_{CC} = 2.7 V
 - 0.50 Ω (typical) at V_{CC} = 4.3 V
- Break-before-make switching
- High noise immunity
- ESD protection:
 - MIL-STD-883, method 3015 Class 3A exceeds 7500 V
 - HBM JESD22-A114F Class 3A exceeds 7500 V
 - MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0 Ω)
 - CDM AEC-Q100-011 revision B exceeds 1000 V
 - IEC61000-4-2 contact discharge exceeds 8000 V for switch ports
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD78 Class II Level A
- Direct interface with TTL levels at 3.0 V
- Control input accepts voltages above supply voltage
- High current handling capability (350 mA continuous current under 3.3 V supply)



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3. Applications

- Cell phone
- PDA
- Portable media player

4. Ordering information

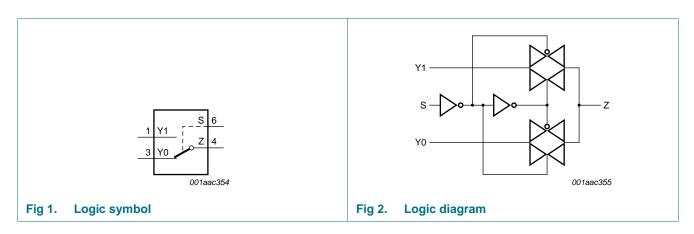
Table 1. Ordering information											
Type number Package											
	Temperature range	Name	Description	Version							
NX3L1G3157GW-Q100	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363							

5. Marking

Table 2. Marking codes ^[1]	
Type number	Marking code
NX3L1G3157GW-Q100	MJ

[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

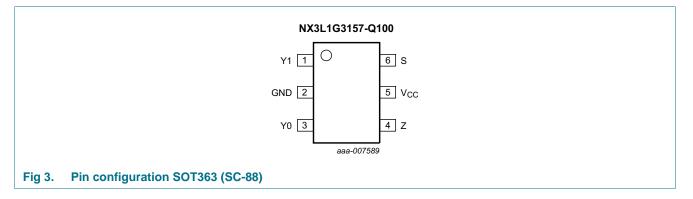
6. Functional diagram



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7. Pinning information

7.1 Pinning



7.2 Pin description

SymbolPinDescriptionY11independent input or outputGND2ground (0 V)Y03independent input or outputZ4common output or inputVcc5supply voltageS6select input	Table 3.	Pin description	
GND2ground (0 V)Y03independent input or outputZ4common output or inputV _{CC} 5supply voltage	Symbol	Pin	Description
Y03independent input or outputZ4common output or inputV _{CC} 5supply voltage	Y1	1	independent input or output
Z 4 common output or input V _{CC} 5 supply voltage	GND	2	ground (0 V)
V _{CC} 5 supply voltage	Y0	3	independent input or output
	Z	4	common output or input
S 6 select input	V _{CC}	5	supply voltage
	S	6	select input

8. Functional description

Table 4.Function table^[1]

Input S	Channel on
L	YO
Н	Y1

[1] H = HIGH voltage level; L = LOW voltage level.

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9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		-0.5	+4.6	V
VI	input voltage	select input S	<u>[1]</u> –0.5	+4.6	V
V _{SW}	switch voltage		<u>[2]</u> –0.5	$V_{CC} + 0.5$	V
I _{IK}	input clamping current	$V_{l} < -0.5 V$	-50	-	mA
I _{SK}	switch clamping current	$V_l < -0.5$ V or $V_l > V_{CC}$ + 0.5 V	-	±50	mA
I _{SW}	switch current	V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; source or sink current	-	±350	mA
		V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 \text{ °C to } +125 \text{ °C}$	[3] _	250	mW

[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

[3] For SC-88 package: above 87.5 °C the value of Ptot derates linearly with 4.0 mW/K.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage		1.4	4.3	V
VI	input voltage	select input S	0	4.3	V
V _{SW}	switch voltage		<u>[1]</u> 0	V _{CC}	V
T _{amb}	ambient temperature		-40	+125	°C
$\Delta t / \Delta V$	input transition rise and fall rate	V_{CC} = 1.4 V to 4.3 V	[2] _	200	ns/V

[1] To avoid sinking GND current from terminal Z when switch current flows in terminal Yn, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current flows from terminal Yn. In this case, there is no limit for the voltage drop across the switch.

[2] Applies to control signal levels.

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11. Static characteristics

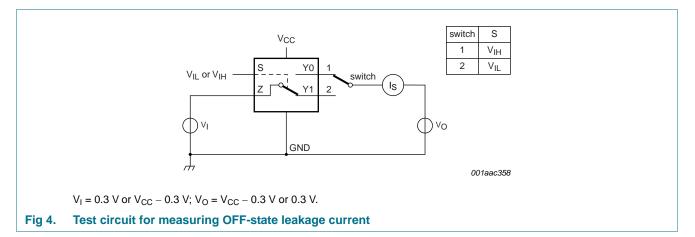
Table 7. Static characteristics

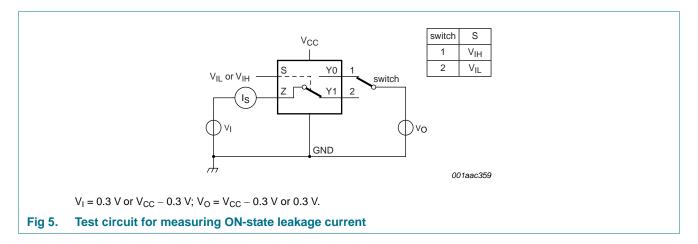
At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions	Tar	_{nb} = 25	°C	T _{amb} = -	–40 °C to	+125 °C	Unit
			Min	Тур	Мах	Min	Max (85 °C)	Max (125 °C)	
V _{IH} H	HIGH-level	$V_{CC} = 1.4 \text{ V} \text{ to } 1.95 \text{ V}$	$0.65V_{CC}$	-	-	$0.65V_{CC}$	-	-	V
	input voltage	V_{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	-	V
		V_{CC} = 2.7 V to 3.6 V	2.0	-	-	2.0	-	-	V
		V_{CC} = 3.6 V to 4.3 V	$0.7V_{CC}$	-	-	$0.7V_{CC}$	-	-	V
V _{IL}	LOW-level	$V_{CC} = 1.4 \text{ V} \text{ to } 1.95 \text{ V}$	-	-	$0.35V_{CC}$	-	$0.35V_{CC}$	$0.35V_{CC}$	V
	input voltage	V_{CC} = 2.3 V to 2.7 V	-	-	0.7	-	0.7	0.7	V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	-	-	0.8	-	0.8	0.8	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	$0.3V_{CC}$	-	$0.3V_{CC}$	$0.3V_{CC}$	V
I _I	input leakage current	select input S; V _I = GND to 4.3 V; V _{CC} = 1.4 V to 4.3 V	-	-	-	-	±0.5	±1	μΑ
I _{S(OFF)}	OFF-state leakage	Y0 and Y1 port; see <u>Figure 4</u>							
	current	V_{CC} = 1.4 V to 3.6 V	-	-	±5	-	±50	±500	nA
		V_{CC} = 3.6 V to 4.3 V	-	-	±10	-	±50	±500	nA
I _{S(ON)}	ON-state	Z port; see Figure 5							
	leakage current	V_{CC} = 1.4 V to 3.6 V	-	-	±5	-	±50	±500	nA
	current	V_{CC} = 3.6 V to 4.3 V	-	-	±10	-	±50	±500	nA
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{SW} = GND$ or V_{CC}							
		$V_{CC} = 3.6 V$	-	-	100	-	690	6000	nA
		$V_{CC} = 4.3 V$	-	-	150	-	800	7000	nA
CI	input capacitance		-	1.0	-	-	-	-	pF
$C_{\text{S(OFF)}}$	OFF-state capacitance		-	35	-	-	-	-	pF
C _{S(ON)}	ON-state capacitance		-	130	-	-	-	-	pF

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11.1 Test circuits





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11.2 ON resistance

Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 7 to Figure 13.

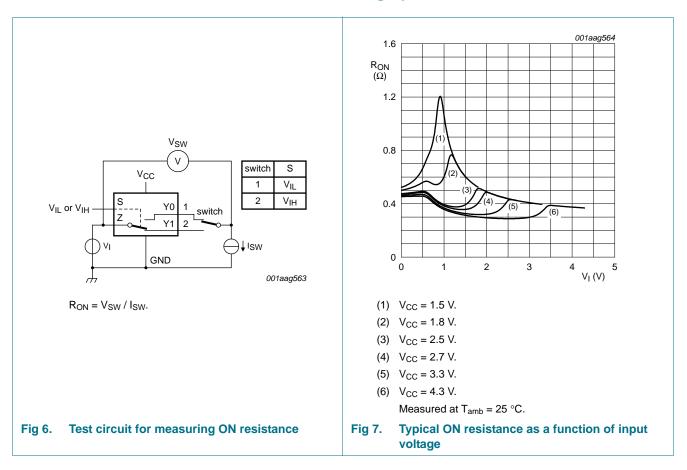
Symbol	Parameter	Conditions	T _{amb} = -	–40 °C to	+85 °C	T_{amb} = -40 °	C to +125 °C	Unit
			Min	Typ <mark>[1]</mark>	Max	Min	Max	
R _{ON(peak)}	ON resistance (peak)	$V_I = GND$ to V_{CC} ; $I_{SW} = 100 \text{ mA}$; see Figure 6						
		$V_{CC} = 1.4 V$	-	1.6	3.7	-	4.1	Ω
		V _{CC} = 1.65 V	-	1.0	1.6	-	1.7	Ω
		$V_{CC} = 2.3 V$	-	0.55	0.8	-	0.9	Ω
		$V_{CC} = 2.7 V$	-	0.5	0.75	-	0.9	Ω
		$V_{CC} = 4.3 V$	-	0.5	0.75	-	0.9	Ω
ΔR_{ON}	ON resistance mismatch between channels	$V_I = GND \text{ to } V_{CC};$ [2] $I_{SW} = 100 \text{ mA}$						
		$V_{CC} = 1.4 V$	-	0.04	0.3	-	0.3	Ω
		V _{CC} = 1.65 V	-	0.04	0.2	-	0.3	Ω
		$V_{CC} = 2.3 V$	-	0.02	0.08	-	0.1	Ω
		$V_{CC} = 2.7 V$	-	0.02	0.075	-	0.1	Ω
		$V_{CC} = 4.3 V$	-	0.02	0.075	-	0.1	Ω
R _{ON(flat)}	ON resistance (flatness)	$V_I = GND \text{ to } V_{CC};$ [3] $I_{SW} = 100 \text{ mA}$						
		$V_{CC} = 1.4 V$	-	1.0	3.3	-	3.6	Ω
		V _{CC} = 1.65 V	-	0.5	1.2	-	1.3	Ω
		$V_{CC} = 2.3 V$	-	0.15	0.3	-	0.35	Ω
		$V_{CC} = 2.7 V$	-	0.13	0.3	-	0.35	Ω
		V_{CC} = 4.3 V	-	0.2	0.4	-	0.45	Ω

[1] Typical values are measured at $T_{amb} = 25 \ ^{\circ}C$.

[2] Measured at identical V_{CC}, temperature and input voltage.

[3] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V_{CC} and temperature.

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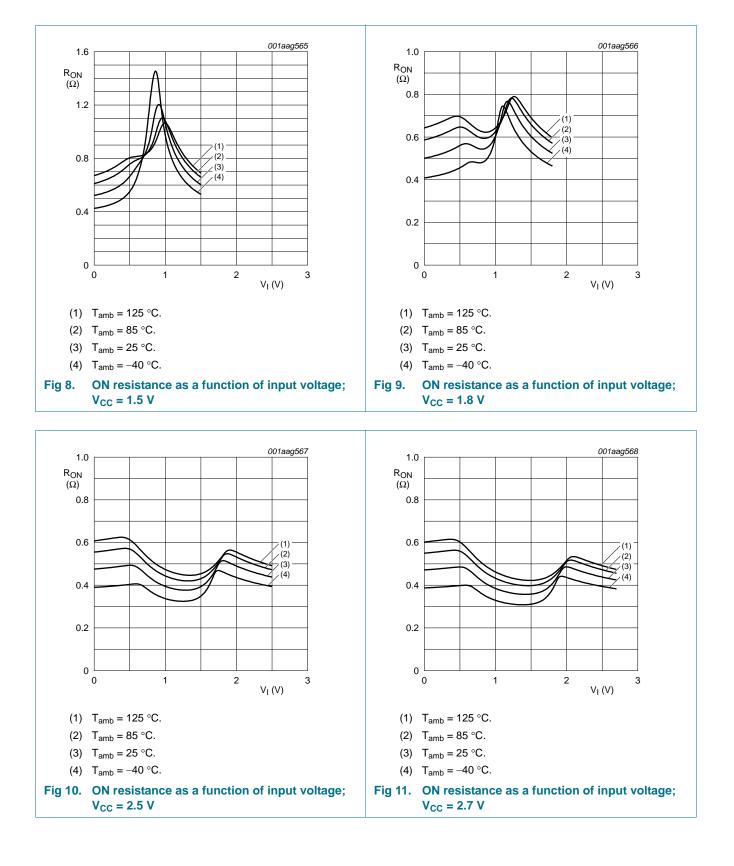


11.3 ON resistance test circuit and graphs

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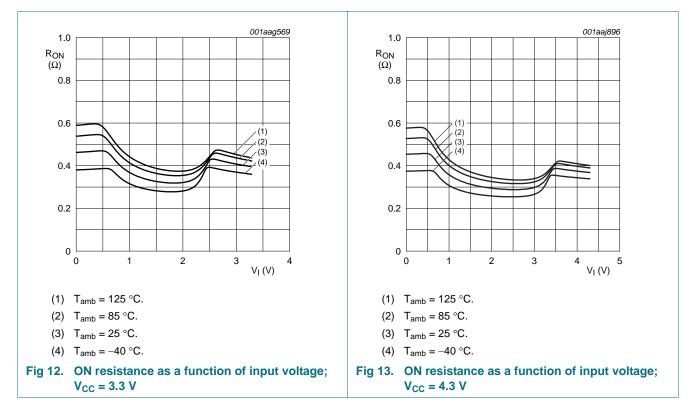
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12. Dynamic characteristics

Table 9. Dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 16.

Symbol	Parameter	Conditions	Ta	_{mb} = 25	°C	T _{amb} =	–40 °C to	+125 °C	Unit
			Min	Тур <u>^[1]</u>	Max	Min	Max (85 °C)	Max (125 °C)	
t _{en}	enable time	S to Z or Yn; see <u>Figure 14</u>							
		V_{CC} = 1.4 V to 1.6 V	-	28	43	-	48	52	ns
		V_{CC} = 1.65 V to 1.95 V	-	23	35	-	38	42	ns
		V_{CC} = 2.3 V to 2.7 V	-	17	27	-	29	32	ns
		V_{CC} = 2.7 V to 3.6 V	-	14	25	-	27	30	ns
		V_{CC} = 3.6 V to 4.3 V	-	14	25	-	27	30	ns
t _{dis}	disable time	S to Z or Yn; see <u>Figure 14</u>							
		V_{CC} = 1.4 V to 1.6 V	-	9	20	-	25	30	ns
		V_{CC} = 1.65 V to 1.95 V	-	6	15	-	20	23	ns
		V_{CC} = 2.3 V to 2.7 V	-	5	11	-	14	16	ns
		V_{CC} = 2.7 V to 3.6 V	-	4	10	-	12	14	ns
		V_{CC} = 3.6 V to 4.3 V	-	4	10	-	12	14	ns

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Symbol	Parameter	Conditions		T _{amb} = 25 °C		T _{amb} =	–40 °C to	+125 °C	Unit	
				Min	Typ <mark>[1]</mark>	Мах	Min	Max (85 °C)	Max (125 °C)	-
t _{b-m} break-before-make time	see Figure 15	[2]					•			
	time	$V_{CC} = 1.4 \text{ V} \text{ to } 1.6 \text{ V}$		-	19	-	4	-	-	ns
		V_{CC} = 1.65 V to 1.95 V		-	17	-	4	-	-	ns
		V_{CC} = 2.3 V to 2.7 V		-	13	-	2	-	-	ns
		V_{CC} = 2.7 V to 3.6 V		-	10	-	2	-	-	ns
		V_{CC} = 3.6 V to 4.3 V		-	10	-	2	-	-	ns

Table 9. Dynamic characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 16.

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.5 V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

[2] Break-before-make guaranteed by design.

12.1 Waveform and test circuits

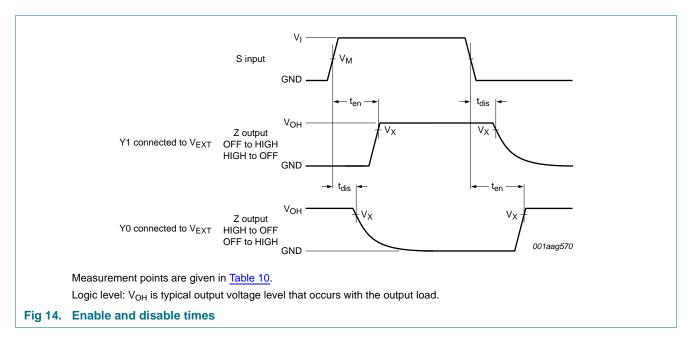
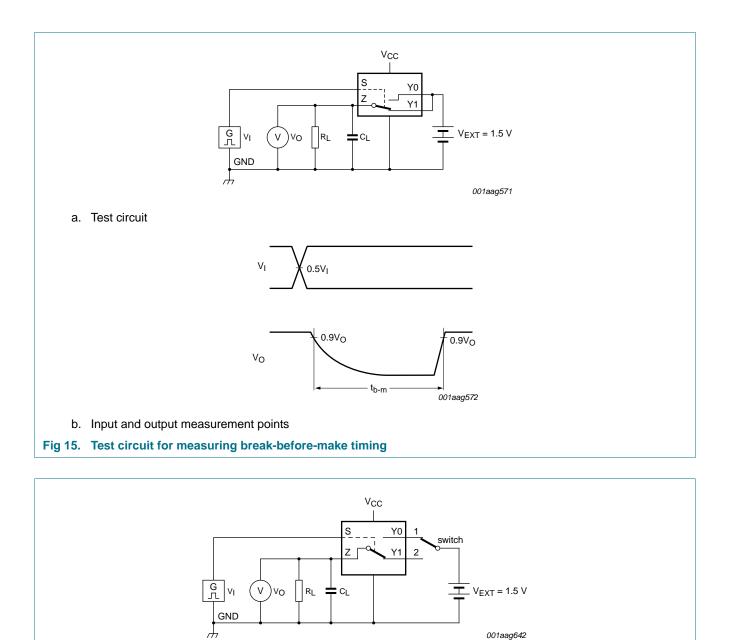


Table 10. Measurement points

Supply voltage	Input	Output
V _{CC}	V _M	V _X
1.4 V to 4.3 V	0.5V _{CC}	0.9V _{OH}

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Definitions test circuit: R_L = Load resistance.

Test data is given in Table 11.

- C_L = Load capacitance including jig and probe capacitance.
- V_{EXT} = External voltage for measuring switching times.

Fig 16. Load circuit for switching times

Table 11. Test data

Supply voltage	e Input Load			
V _{cc}	V _I t _r , t _f		CL	RL
1.4 V to 4.3 V	V _{CC}	\leq 2.5 ns	35 pF	50 Ω

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12.2 Additional dynamic characteristics

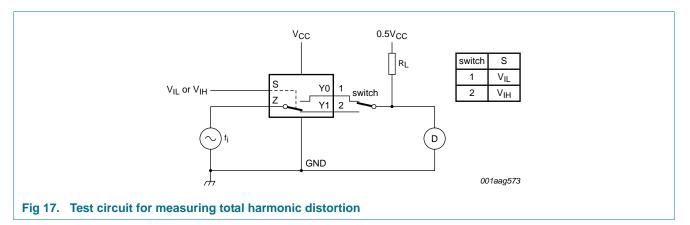
Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); $V_I = GND$ or V_{CC} (unless otherwise specified); $t_r = t_f \le 2.5$ ns; $T_{amb} = 25$ °C.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
THD	total harmonic distortion	$f_i = 20 \text{ Hz to } 20 \text{ kHz}; \text{ R}_L = 32 \Omega; \text{ see } \frac{\text{Figure } 17}{1000 \text{ sec } 17}$	[1]			
		V _{CC} = 1.4 V; V _I = 1 V (p-p)	-	0.15	-	%
		V _{CC} = 1.65 V; V _I = 1.2 V (p-p)	-	0.10	-	%
		V _{CC} = 2.3 V; V _I = 1.5 V (p-p)	-	0.02	-	%
		$V_{CC} = 2.7 \text{ V}; \text{ V}_{I} = 2 \text{ V} (p-p)$	-	0.02	-	%
		V _{CC} = 4.3 V; V _I = 2 V (p-p)	-	0.02	-	%
f _(-3dB)	–3 dB frequency response	$R_L = 50 \Omega$; see Figure 18	<u>[1]</u>			
		$V_{CC} = 1.4 \text{ V} \text{ to } 4.3 \text{ V}$	-	60	-	MHz
α_{iso}	isolation (OFF-state)	$f_i = 100 \text{ kHz}; R_L = 50 \Omega; \text{ see } \frac{\text{Figure 19}}{100 \text{ kHz}}$	<u>[1]</u>			
		$V_{CC} = 1.4 \text{ V} \text{ to } 4.3 \text{ V}$	-	-90	-	dB
V _{ct}	crosstalk voltage	between digital inputs and switch; $f_i = 1 \text{ MHz}$; $C_L = 50 \text{ pF}$; $R_L = 50 \Omega$; see Figure 20				
		V _{CC} = 1.4 V to 3.6 V	-	0.2	-	V
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	0.3	-	V
Q _{inj}	charge injection	$f_i = 1 \text{ MHz}; C_L = 0.1 \text{ nF}; R_L = 1 \text{ M}\Omega; V_{gen} = 0 \text{ V}; R_{gen} = 0 \Omega; \text{ see } \frac{\text{Figure 21}}{2}$				
		V _{CC} = 1.5 V	-	3	-	рС
		V _{CC} = 1.8 V	-	4	-	рС
		$V_{CC} = 2.5 V$	-	6	-	рС
		V _{CC} = 3.3 V	-	9	-	pC
		$V_{CC} = 4.3 V$	-	15	-	рС

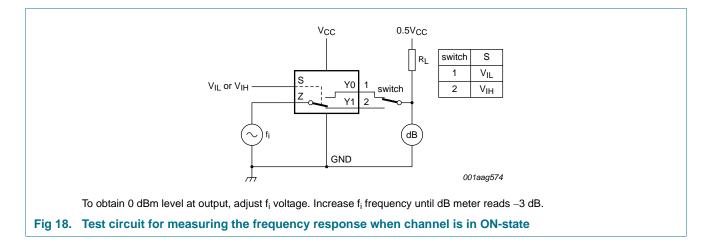
[1] f_i is biased at 0.5V_{CC}.

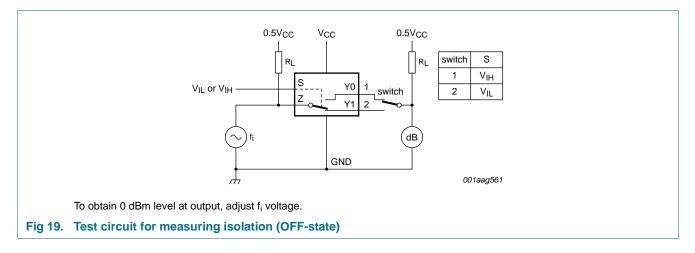
12.3 Test circuits



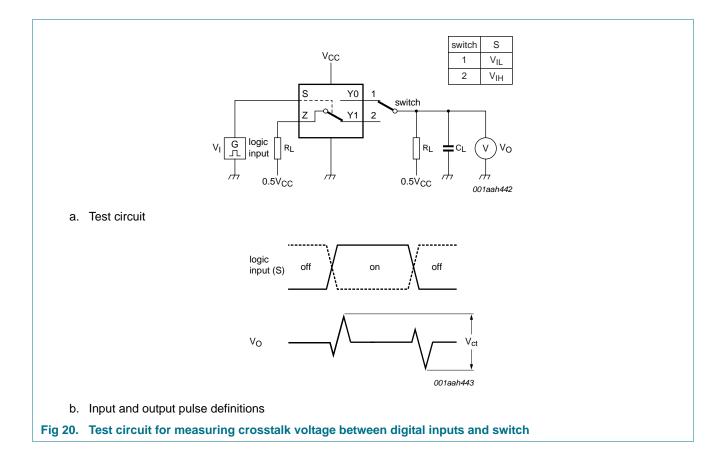
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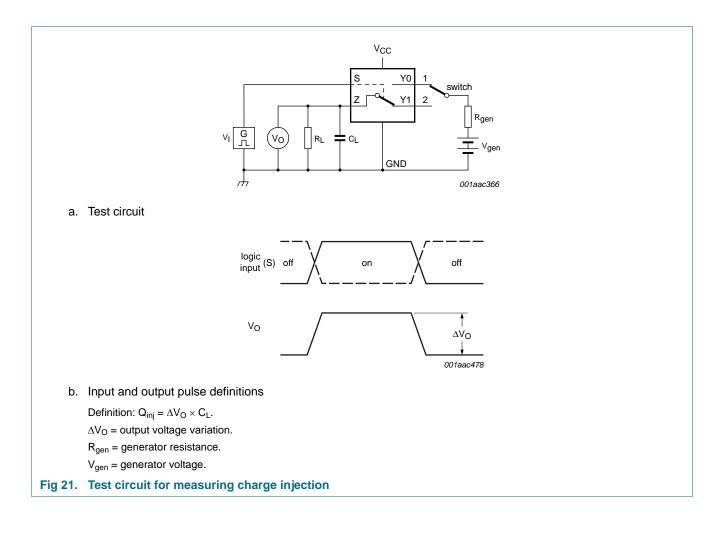


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13. Package outline

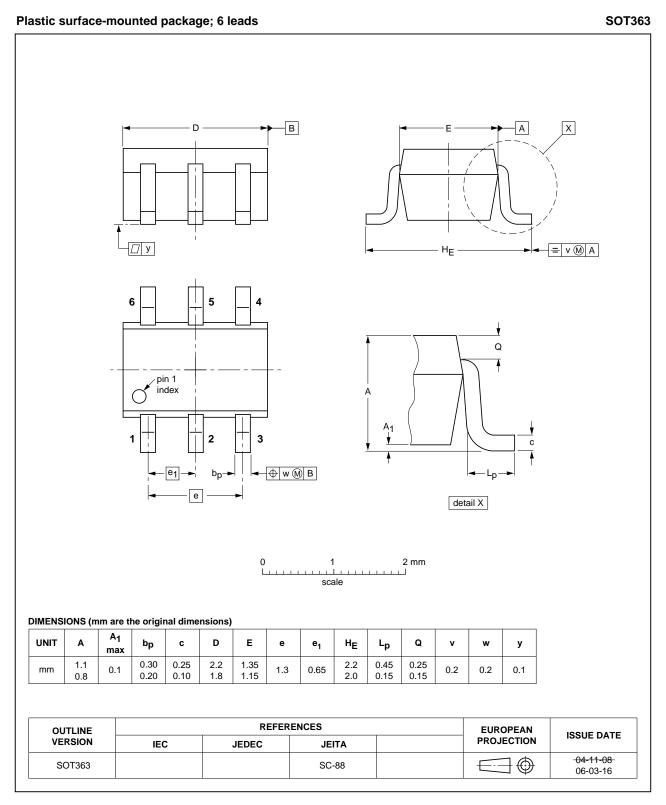


Fig 22. Package outline SOT363 (SC-88)

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14. Abbreviations

Acronym	Description
0014	
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
HBM	Human Body Model
MIL	Military
MM	Machine Model
PDA	Personal Digital Assistant
TTL	Transistor-Transistor Logic

15. Revision history

Table 14. Revision history				
Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3L1G3157_Q100 v.1	20130523	Product data sheet	-	-

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16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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